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Low-energy x-ray detection with JUNGFRAU

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Presented at the 23rd International Workshop on Radiation Imaging Detectors, June 2022, *<u>viktoria.hinger@psi.ch</u>

Applications of JUNGFRAU

At free-electron lasers (FEL)

- Original field of application for JUNGFRAU
- Short (fs), intense x-ray pulses

Facilities operating JUNGFRAU

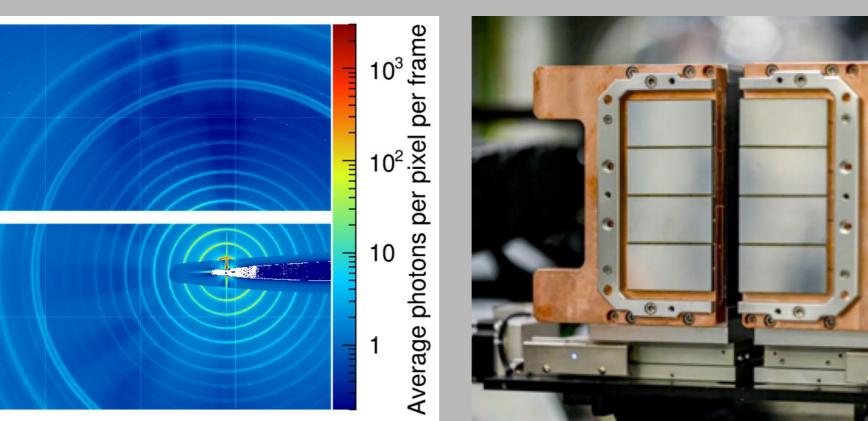
European XFEL

At synchrotrons

- **Fast, time-resolved** experiments
- Applications, for which charge sharing and

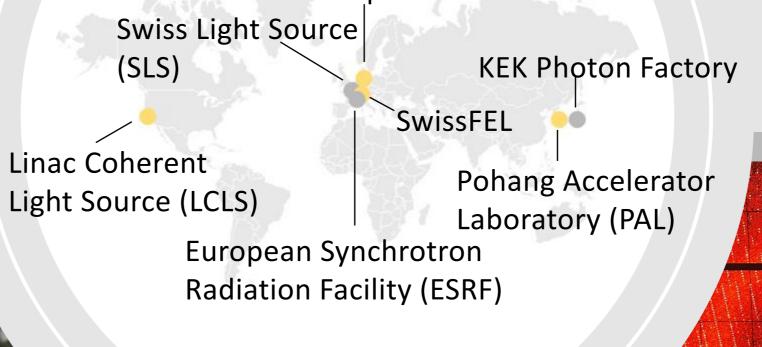


Probe electronic structure of materials



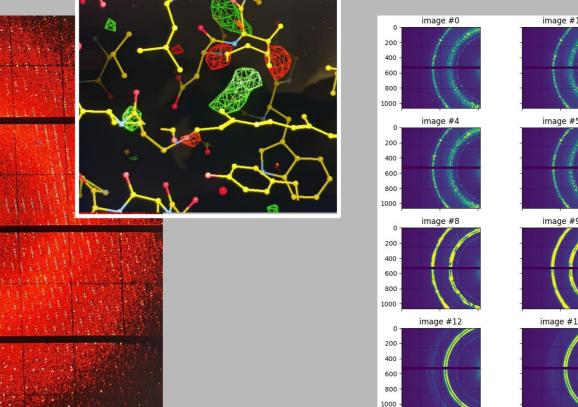
Powder diffraction at LCLS





XFEL Synchrotron

pileup limit the capabilities of photon counting detectors [1]



Serial crystallography with **1 ms time resolution** (visiting MAX IV, Sweden)

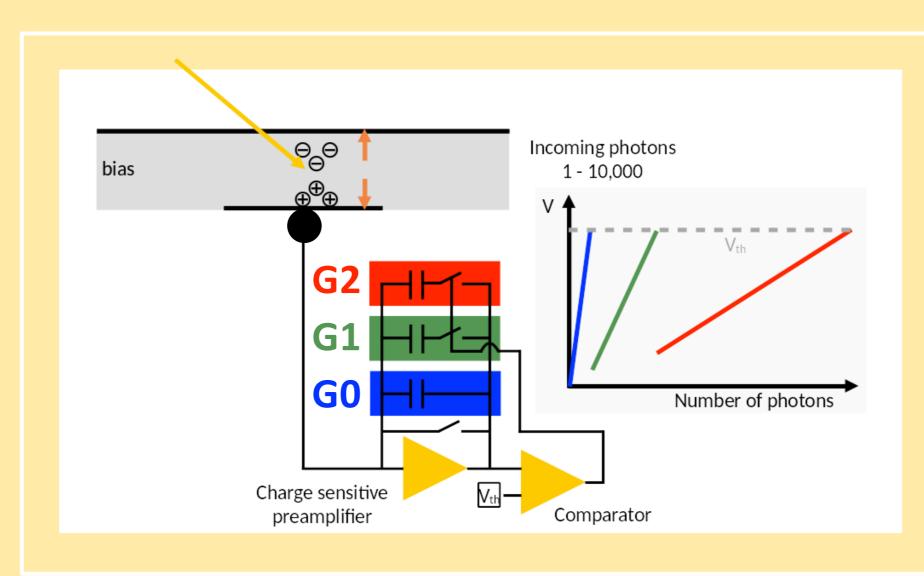
Phase transition of Sn, measured with **7** µs burst mode at ESRF ID09

JUNGFRAU in a nutshell

Sensitive from 1 – 10⁵ photons from 1.2 keV – 12 keV per pixel per image, no matter when the photons arrive

How is it possible?

Charge-integrating hybrid pixel detector (75 \times 75 μ m²) Three dynamically switching linear gains per pixel Noise below Poisson limit over full range



JUNGFRAU 1.1

- Newest ASIC version
- Improved output linearity Noise reduced from 52 e⁻ (version 1.0) to < **34** e⁻ in high gain

Maximum frame rate 2.2 kHz

JUNGFRAU pixel schematic with dynamic gain switching architecture

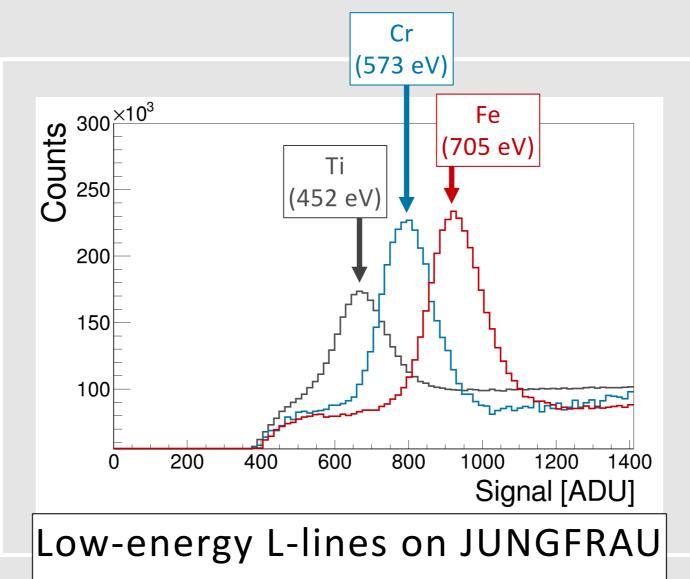
Poster by M. Carulla

Entering new territory: Soft x-ray detection **First results are looking strong!**

Talk by J. Zhang

Thin entrance window (TEW)

- Improve quantum efficiency (QE) at low energies
- First system at SwissFEL Maloja using JUNGFRAU 1.1 and TEW sensors
 - → Enables single photon detection down to 800 eV



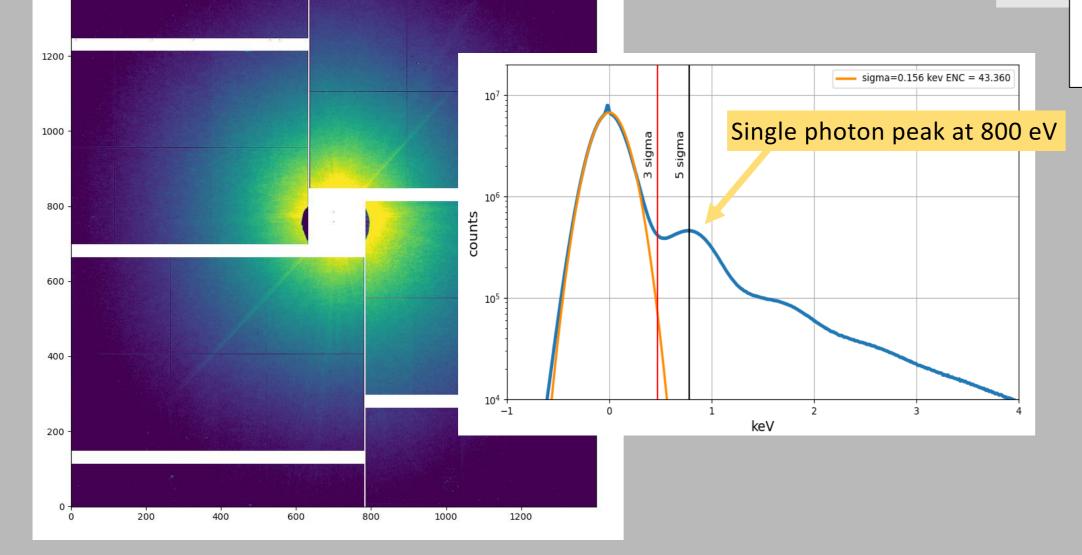
Low gain avalanche diode (LGAD)

- Sensors with intrinsic gain ~ 10
- Inverse LGAD (iLGAD) with TEW
 - \rightarrow Cooling required due to leakage current

ENC 2d (electrons)

- \rightarrow Noise ~ 5 e⁻ (-20°C, 5 µs exposure)
- \rightarrow Will enable single photon detection down to ~ 250 eV

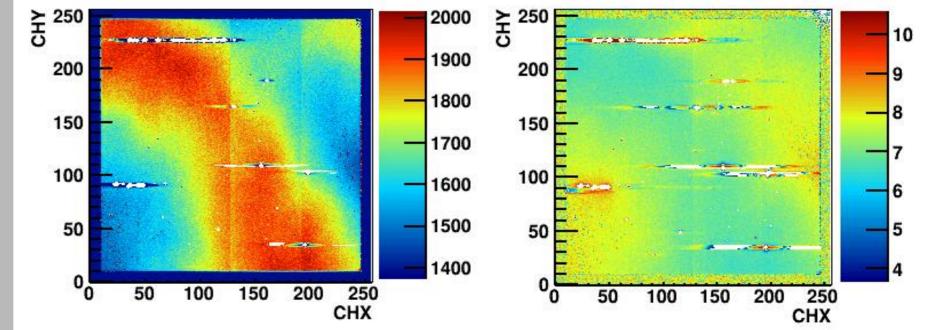
gain 2d (ADC/keV)



iLGAD in high gain (2×2 clusters, -22°C, 10 μ s exposure) QE [%] Energy [eV]

Scattering of 800 eV x-rays on xenon clusters with JUNGFRAU 1.1 and TEW at SwissFEL Maloja [2]

Comparison of QE for standard and TEW/iLGAD sensors





2D gain and ENC pixel map on JUNGFRAU iLGAD (Ti fluorescence at -22°C, exposure 10 µs)

iLGAD bonded to JUNGFRAU 1.1 ASIC



This project has received funding from the European Union's Horizon 2020 research and innovation programme under the Marie Skłodowska-Curie grant agreement No 884104 (PSI-FELLOW-III-3i).

[1] F. Leonarski *et al. Nat. Methods* **15,** 799–804 (2018) [2] V. Hinger *et al. J. Instrum.* (forthcoming)